

DXG2PH50B-20N

RF Power GaN Transistor

1. Product profile

dynax

1.1 General description

DXG2PH50B-20N is a 20 W RF GaN HEMT Transistor with second generation RF GaN technology from Dynax, which is ideal for cellular base station applications at frequencies from 4400 MHz to 5000 MHz.

Table 1. Typical performance ¹

Freq	P _{sat} ²	P _{avg} ³	η _□ ³	G _P ³
(MHz)	(dBm)	(dBm)	(%)	(dB)
4900	42.8	47.8	37.0	

 $^{^{1}}$ Typical performance in Dynax Demo with the device soldered onto the heatsink, test condition: $V_{DS} = 48 \text{ V}$, $I_{DQ} = 30 \text{ mA}$

1.2 Features and benefits

- > High efficiency, high gain
- > Internally matched for broadband performance
- > Designed for Digital Pre-Distortion error correction systems

1.3 Applications

RF power amplifier for base stations in the 4400 MHz to 5000 MHz frequency range

1.4 Lead-free and RoHS compliant



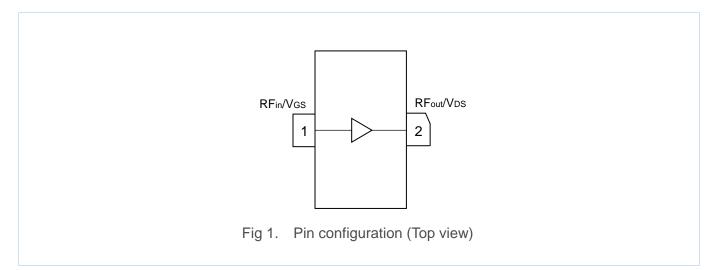


² Test condition: Input signal Pulsed CW, Pulse width = 100 μs, Duty cycle = 10 %.

³ Test condition: Single-Carrier W-CDMA, IQ magnitude clipping, Input signal PAR = 7.5 dB @ 0.01 % probability on CCDF. ACPR measured in 3.84 MHz channel bandwidth @ ±5 MHz offset.



2. Pinning information



3. Ordering information

Table 2. Ordering information

Part number	Marking	Package type	Packaging information	
			Tray: Suffix = 20 units	
DXG2PH50B-20N	DC2B	DFN 4×4.5mm	Tape and Reel:	
DAG21 1130B-2011	D02B			
			13-inch Reel	

4. Maximum ratings

Table 3. Maximum ratings

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DSS}	150	V
Gate-Source Voltage	V _G S	-10 ~ +2	V
Operating Voltage	V _{DS}	0 ~ +55	V
Maximum Forward Gate Current	IGMAX	1.8	mA
Storage Temperature Range	T _{STG}	- 65 ~ +150	°C
Operating Junction Temperature	TJ	225	°C
Absolute Maximum Channel Temperature ¹	T _{MAX}	275	°C

¹ Functional operation above 225°C has not been characterized and is not implied. Operation at T_{MAX} (275°C) reduces median time to failure by an order of magnitude; Operation beyond T_{MAX} could cause permanent damage.



5. Thermal characteristics

Table 4. Thermal characteristics

Parameter	Symbol	Value	Unit
Thermal Resistance at Average Power by Infrared Measurement,			
Active Die Surface-to-Case	R _{thjc} (IR)	7.2	°C/W
$T_{base-plate} = 85^{\circ}C$, $P_D = 7.7 \text{ W}$			
Thermal Resistance at Average Power by Finite Element Analysis,			
Junction-to-Case	$R_{thjc}(FEA)$	10.8	°C/W
$T_{\text{base-plate}} = 85^{\circ}\text{C}, P_{D} = 7.7 \text{ W}$			

6. Electrical characteristics (TA = 25°C unless otherwise noted)

Table 5. DC characteristics

Parameter	Symbol	Min.	Тур.	Max.	Unit
Drain-Source Leakage Current (V _{GS} = -10 V, V _{DS} = 150 V)	I _{DSS}	-	-	1.8	mA
Drain-Source Breakdown Voltage (V _{GS} = -10 V, I _D = 1.8 mA)	V _{(BR)DSS}	150	-	-	V
Gate Threshold Voltage (V _{DS} = 48 V, I _D = 1.8 mA)	V _{GS(th)}	-4.0	-3.3	-1.0	V
Gate Quiescent Voltage $(V_{DS} = 48 \text{ V}, I_D = 30 \text{ mA})$	V _{GS(Q)}	-	-3.0	-	V



7. Test information

7.1 Pulsed CW

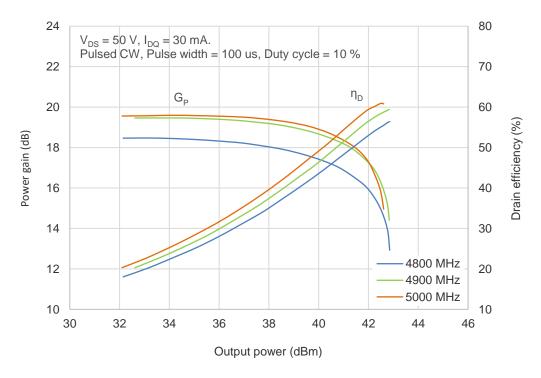


Fig 2. Power gain, Drain efficiency vs. Pulse output power



8. Impedance information

Table 6. Typical impedance ¹

Maximum Output Power							
Freq (MHz)	Z _S (Ω)	$Z_{L}\left(\Omega \right)$	G _P (dB)	P _{sat} (dBm)	P _{sat} (W)	η _D (%)	
4880	8.0 - j10.0	31.7 + j53.1	21.5	43.1	20.4	65.0	
	Maximum Drain Efficiency						
Freq (MHz)	Z _S (Ω)	Z _L (Ω)	G _P (dB)	P _{sat} (dBm)	P _{sat} (W)	η₀ (%)	
4880	8.0 - j10.0	28.0 + j73.1	23.5	41.7	14.8	73.0	

 $^{^{1}}$ VDS = 48 V, IDQA = 30 mA, Pulsed CW, Pulse width = 100 μ s, Duty cycle = 10 %.

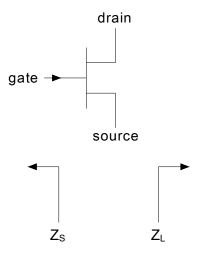


Fig 3. Definition of transistor impedance



9. Median lifetime

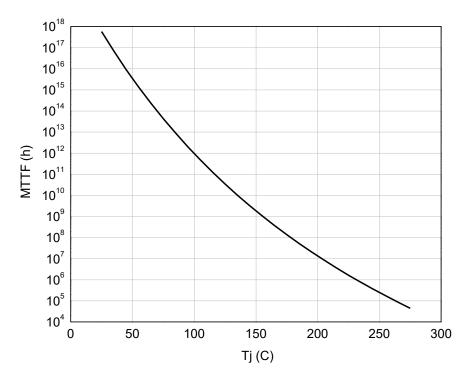
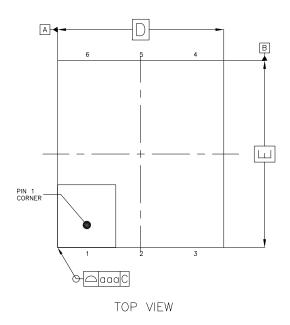
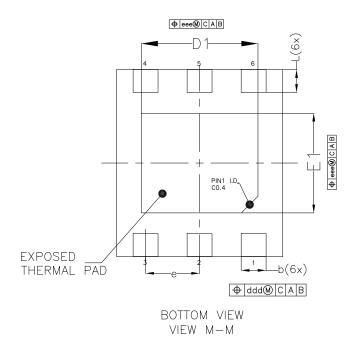


Fig 4. Median lifetime vs. channel temperature



10. Package outline





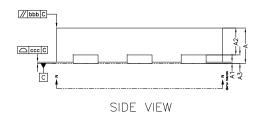


Fig 5. Package outline —— DFN 4x 4.5mm

Table 7. Package dimensions

DESCRIPTION		DIM		MILLIMETER		
		DIM	MIN NOM		MAX	
TOTAL THICKNESS		А	0.80	0.85	0.93	
STAND OFF		A1	0.00		0.08	
MOLD THICKNESS		A2	0.60	0.65	0.73	
L/F THICKNESS		A3	0.203 REF			
BODY SIZE	Χ	D	3.95	4.00	4.08	
DODT SIZE	Υ	Е	4.45	4.50	4.58	
LEAD PITCH		е	1.30 BSC			
LEAD WIDTH		b	0.55	0.60	0.68	
LEAD LENGTH		L	0.50	0.55	0.63	
EP SIZE	0.0175		2.76	2.81	2.89	
EP SIZE		E1	2.35	2.40	2.48	
Tolerance of form and position						
PACKAGE EDGE TOLERANCE		aaa	0.1			
MOLD FLATNESS		bbb	0.1			



(Continued)

DESCRIPTION	DIM		MILLIMETER	
DESCRIPTION	DIM	MIN	NOM	MAX
LEAD COPLANARITY	ccc		0.08	
LEAD POSITION OFFSET	ddd		0.1	
EXPOSED PAD OFFSET	eee		0.1	

11. Abbreviations

Table 8. Abbreviations

Acronym	Description
CW	Continuous Waveform
ESD Electro-Static Discharge	
GaN Gallium Nitride	
HEMT	High Electron Mobility Transistor
MTTF	Median Time To Failure
VSWR	Voltage Standing Wave Ratio

12. Legal information

12.1 Datasheet status

Document status	Product Status	Definition
Objective [short] datashoot	Engineering	This document contains data from the objective specification
Objective [short] datasheet	Sample	for product development.
Droliminary [short] datasheet	Engineering	This document contains data from the preliminary
Preliminary [short] datasheet	Sample	specification.
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